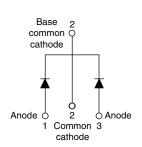


VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

Schottky Rectifier, 2 x 10 A

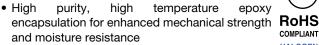




PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 10 A			
V_R	150 V			
V _F at I _F	0.66 V			
I _{RM} max.	5 mA at 125 °C			
T _J	175 °C			
Diode variation	Common cathode			
E _{AS}	2.45 mJ			

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	20	Α		
V _{RRM}		150	V		
I _{FSM}	t _p = 5 μs sine	1030	Α		
V _F	10 A _{pk} , T _J = 125 °C (per leg)	0.66	V		
T _J	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-20CTQ150PbF	VS-20CTQ150-N3	UNITS	
Maximum DC reverse voltage	V _R	150	150	V	
Maximum working peak reverse voltage	V _{RWM}	150	130	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg		50 % duty cycle at T _C = 154 °C, rectangular waveform		10	Α
See fig. 5 per device	I _{F(AV)}			20	
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load	1030	А
non-repetitive surge current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	180	
Non-repetitive avalanche energy per leg	etitive avalanche energy per leg E_{AS} $T_J = 25$ °C, $I_{AS} = 0.7$ A, L = 10 mH		2.45	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.7	А



VS-20CTQ150PbF, VS-20CTQ150-N3

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	10 A	- T _J = 25 °C	0.80	0.88	
		20 A		0.90	1.0	V
		10 A	- T _J = 125 °C	0.63	0.66	
		20 A		0.73	0.77	
Maximum reverse leakage current per leg		T _J = 25 °C	V_{R} = Rated V_{R}	3.0	25	μΑ
See fig. 2	I _{RM}	T _J = 125 °C	VR = nateu VR	2.7	5.0	mA
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	280	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		-	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		Б	DO	2.0	
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	
Approximate weight				2	g
				0.07	OZ.
Mounting torque —	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220AB	20CT	Q150

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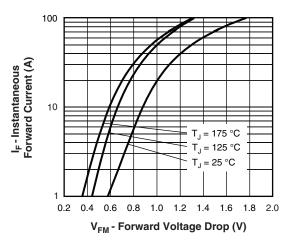


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

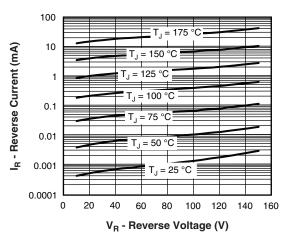


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

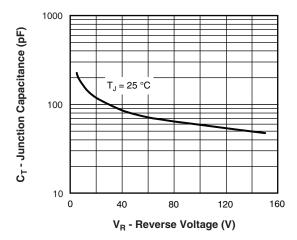


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

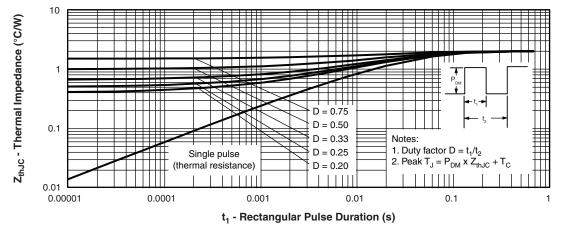


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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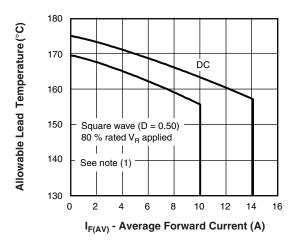


Fig. 5 - Maximum Average Forward Current vs.
Allowable Lead Temperature

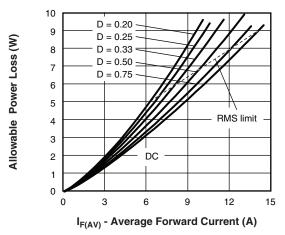


Fig. 6 - Maximum Average Forward Dissipation vs.

Average Forward Current

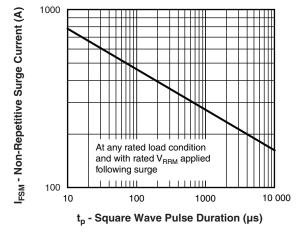


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

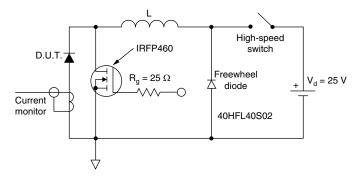


Fig. 8 - Unclamped Inductive Test Circuit

Note

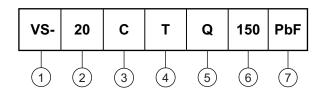
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (20 = 20 A)

Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

Voltage ratings (150 = 150 A)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20CTQ150PbF	50	1000	Antistatic plastic tube		
VS-20CTQ150-N3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95222		
Dout moulding information	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028		



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